TOSHIBA Photocoupler GaAs IRED & Photo-Transistor

# TLP627, TLP627-2, TLP627-4

Programmable Controllers
DC-output Module
Telecommunication

The TOSHIBA TLP627,-2 and -4 consist of a gallium arsenide infrared emitting diode optically coupled to a Darlington connected phototransistor which has an integral base-emitter resistor to optimize switching speed and elevated temperature characteristics.

The TLP627-2 offers two isolated channels in a eight lead plastic DIP, while the TLP627-4 provide four isolated channels per package.

Collector-Emitter Voltage : 300 V (min)
 Current Transfer Ratio : 1000 % (min)
 Isolation Voltage : 5000 Vrms (min)

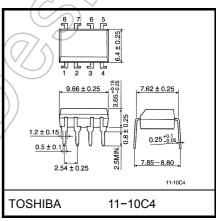
UL Recognized : UL1577, File No.E67349

	Unit: mm
4 3 4 3 5 20 4 4 0 25 1.2 ± 0.15 0.5 ± 0.1 0.5 ± 0.1	7.62±0.25 0.25-0.05 7.85~8.80
TOSHIBA 11	-5B2

Weight: 0.26 g (typ.)

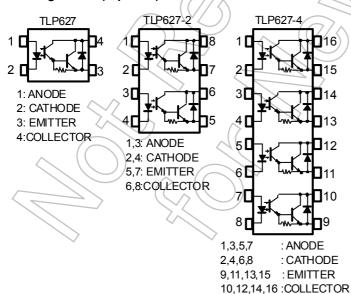
	Made in Jap	oan	Made in Th	ailand
UL Recognized	E67349	*1 (	E152349	/*1
BSI Approved	7426, 7427	*2	7426, 7427	*2

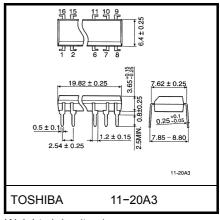
\*1 UL1577



Weight: 0.54 g (typ.)

#### Pin Configuration (top view)





Weight: 1.1 g (typ.)

<sup>\*2</sup> BS EN60065: 2002, BS EN60950-1: 2002



#### Absolute Maximum Ratings (Ta=25°C)

			Ra			
	Characteristics	Symbol	TLP627 TLP627-2 TLP627-4		Unit	
	Forward Current	lF	60	50	mA	
	Forward Current Derating	ΔI <sub>F</sub> /°C	-0.7(Ta≥39°C)	-0.5(Ta≥25°C)	mA /°C	
	Pulse Forward Current	IFP	1(100μs pu	ılse,100pps)	Α	
LED	Power Dissipation (1 Circuit)	PD	100	70	mW	
	Power Dissipation Derating (Ta≥25°C,1 Circuit)	ΔP <sub>D</sub> /°C	-1.0	-0.7	mW /°C	
	Reverse Voltage	V <sub>R</sub>	((//	5	V	
	Junction Temperature	Tj		25	°C	
	Collector-Emitter Voltage	V <sub>CEO</sub>	3	00	V	
	Emitter -Collector Voltage	V <sub>ECO</sub>		0.3	٧	
Detector	Collector Current	IE	1	50	mA	
Dete	Collector Power Dissipation (1 Circuit)	Pc	150(*300)	100	mW	
	Collector Power Dissipation Derating (Ta≥25°C,1 Circuit)	ΔPc/°C	-1.5(*-3.5)	-1,0	mW /°C	
	Junction Temperature	Tj	9	25	°C	
Ope	rating Temperature Range	T <sub>opr</sub>	-55 to 100		°C	
Storage Temperature Range		T <sub>stg</sub>	-55 to 125		°C	
Lead Soldering Temperature (10s)		T <sub>sol</sub>	(260(	10sec)	°C	
Tota	l Package Power Dissipation	РТ	250(*320)	150	mW	
Tota	I Package Power Dissipation Derating (Ta≥25°C,1 Circuit)	ΔP <sub>T</sub> /°C	-2.5(*-3.2)	-1.5	mW /°C	
Isola	tion Voltage (AC,1minute, R.H. ≤ 60%) (Note1)	BVS	)) 50	000	Vrms	

<sup>\*</sup>IF=20mA Max

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note1)Device considered a two terminal device: LED side pins Shorted together and DETECTOR side pins shorted together.

### **Recommended Operating Conditions**

Characteristics	$\Diamond$	Symbol	Min	Тур.	Max	Unit
Supply Voltage	(\frac{1}{2}	Vcc	-	_	200	V
Forward Current		l <sub>F</sub>	-	16	25	mA
Collector Current		IC	-	_	120	mA
Operating Temperature		T <sub>opr</sub>	-25		85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.



### Individual Electrical Characteristics (Ta=25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
LED	Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μΑ
	Capacitance	C <sub>T</sub>	V = 0, f=1MHz	_ <	30	_	pF
	Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = 0.1mA	300		7	٧
tor	Emitter-Collector Breakdown Voltage	V <sub>(BR)ECO</sub>	I <sub>E</sub> = 0.1mA	0.3	$\geq$	_	V
Detector	Collector Dark Current	1	V <sub>CE</sub> = 200V		)10	200	nA
	Collector Dark Current	ICEO	V <sub>CE</sub> = 200V, Ta = 85°C	1		20	μΑ
	Capacitance Collector to Emitter	C <sub>CE</sub>	V=0, f=1MHz		10	) [	рF

## Coupled Electrical Characteristics (Ta=25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Current Transfer Ratio	I <sub>C</sub> /I <sub>F</sub>	I <sub>F</sub> =1mA, V <sub>CE</sub> =1V	1000	4000	_	%
Saturated CTR	I <sub>C</sub> /I <sub>F</sub> (sat)	I <sub>F</sub> =10mA, V <sub>CE</sub> =1V	500		_	%
Collector-Emitter	\/(oot)	I <sub>C</sub> =10mA, I <sub>F</sub> =1mA	(VZ)	/ —	1.0	V
Saturation Voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> =100mA, I <sub>F</sub> =10mA	0.3	_	1.2	٧

## Isolation Electrical Characteristics (Ta=25°C)

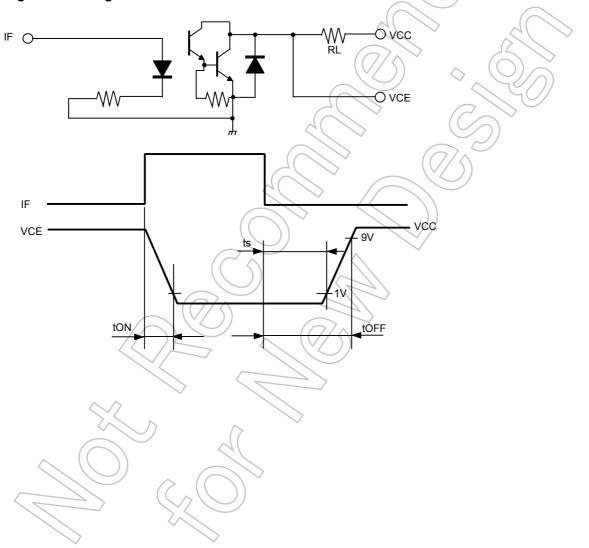
Characteristics	Sŷmbol	Test Condition	Min	Тур.	Max	Unit
Capacitance Input to Output	Cs	V <sub>S</sub> =0, f=1MHz	_	0.8	_	pF
Isolation Resistance	√ R <sub>S</sub>	V <sub>S</sub> =500V, R.H.≤60%	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
		AC, 1minute	5000	_	_	\/ n.m. n
Isolation Voltage	BVS	AC, 1second, in oil	_	10000	_	Vrms
	_	DC, 1 minute, in oil	_	10000	_	Vdc

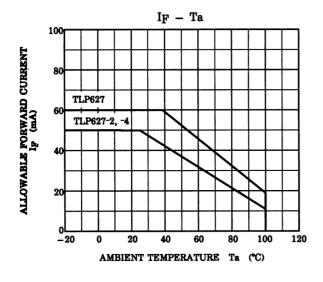


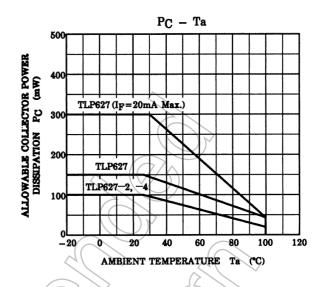
### Switching Characteristics (Ta=25°C)

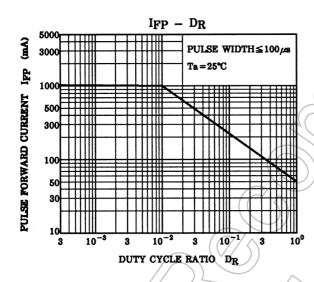
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise Time	t <sub>r</sub>		_	40	_	
Fall Time	t <sub>f</sub>	$V_{CC}$ =10V $I_{C}$ =10mA $R_{L}$ =100 $\Omega$	_	15	_	
Turn-on Time	t <sub>on</sub>		_ <	50	_	
Turn-off Time	t <sub>off</sub>		_	15	_	μs
Turn-on Time	t <sub>ON</sub>	R <sub>L</sub> =180Ω (Fig.1) V <sub>CC</sub> =10V, I <sub>F</sub> =16mA	_	5	)/_	
Strage Time	t <sub>s</sub>		10	40	_	
Turn-off Time	toff		X + X	80	_	

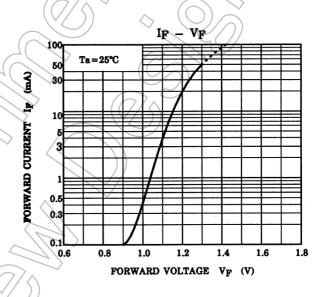


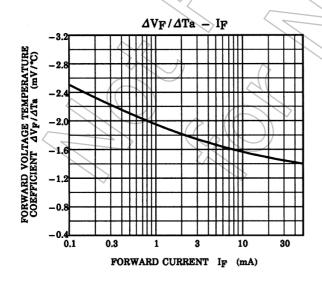


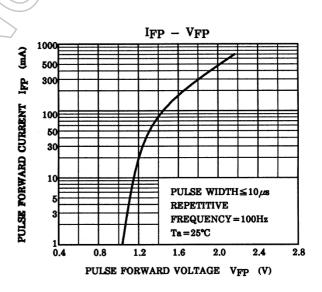


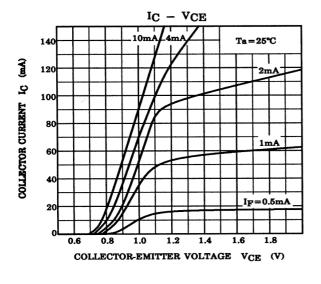


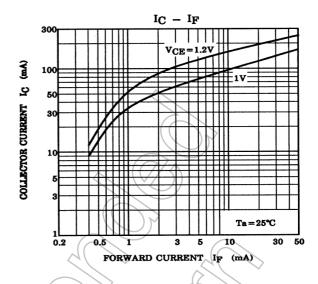


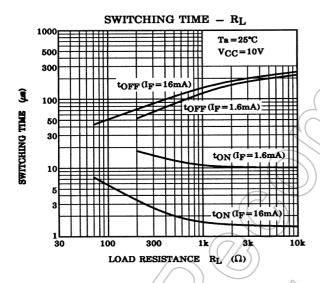


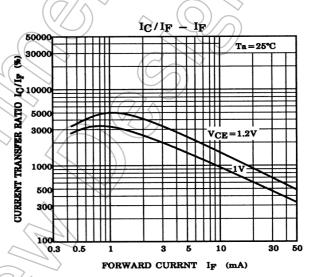


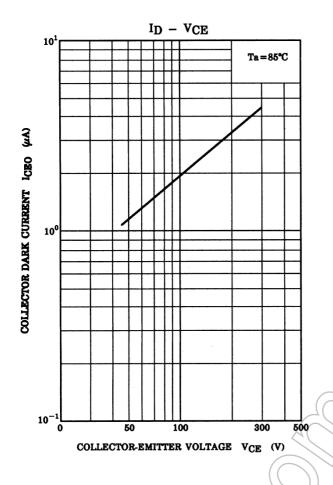


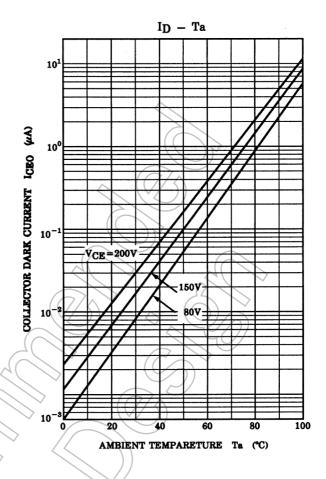


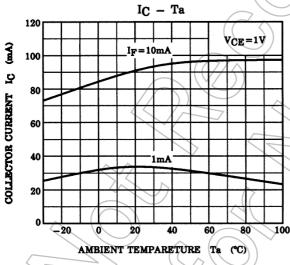


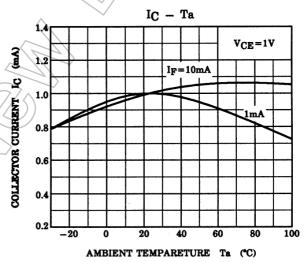












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